

L Number	Hits	Search Text	DB	Time stamp
1	5159	428/212	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:54
2	8	428/212 and 'semiconductor film'	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:55
3	435	428/212 and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:55
4	17	(428/212 and semiconductor) and primer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:55
5	11	(428/212 and semiconductor) and photocatalyst	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:55
6	0	((428/212 and semiconductor) and primer) and ((428/212 and semiconductor) and photocatalyst)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:55
7	14427	"semiconductor film"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:56
8	68	428/212 and "band gap"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:56
9	779	"semiconductor film" and "band gap"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:56
10	0	("semiconductor film" and "band gap") and primer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:56
11	13	("semiconductor film" and "band gap") and photocatalyst	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:57
12	462	("semiconductor film" and "band gap") and oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:57
13	118	((("semiconductor film" and "band gap") and oxide) and titanium	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:57
14	107	((("semiconductor film" and "band gap") and oxide) and titanium) and aluminum	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:58
15	106	((("semiconductor film" and "band gap") and oxide) and titanium) and aluminum) and (thick or thickness)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/05/23 14:59